Technical Parallel Session Advanced Materials for Micro- and Nano-Systems (AMM&NS)

Day 1
Tuesday, 17 January 2006
Location: NUS Campus, Prince George's Park Function Room 3

14:00 - 14:20	Lattice-mismatch and CMOS Eugene A. FITZGERALD
14:20 - 14:40	Enhancement in Indium Incorporation for InGaN Grown on InN Intermediate Layer H. HARTONO
14:40 - 15:00	Dilute nitride-antimonide as a potential material system for communication wavelength photonics on low-cost GaAs platforms S.F. YOON
15:00 - 15:20	Effect of oxygen on Ni-silicided FUSI metal gate H.P. YU
15:20 - 15:40	Nanoanalytical characterization of breakdown spots in ultrathin gate dielectrics K.L. PEY
15:40 - 16:00	Effects of applied loads, effective contact area and surface roughness on the dicing yield of 3D Co bonded interconnects H.L. LEONG
16:00 - 16:20	Tea Break
16:20 - 16:40	Colloid chemistry of self-organizing devices Yet-Ming CHIANG
16:40 - 17:00	Monitoring Defect Formation in Colloidal Self Assembly using Photonic Bandgap Variations Y.K. KOH
17:00 - 17:20	Colloidal Self-Assembly for 3-dimensional Ordered Nanostructures C.C. WONG
17:20 - 17:40	Fabrication of two-dimensional photonic crystals in AlGaInP/GaInP membranes by inductively coupled plasma etching A. CHEN
17:40 - 18 :00	Synthesizing Binary Ionic Colloidal Crystals V. SHARMA
18:00	End of 1 st day Technical Parallel Session

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Day 2 Wednesday, 18 January 2006 Located at NUS Global Classroom, Computer Centre Level 3

9:00 - 9:20	Enabling nanoscale science and engineering via highly flexible, low cost, maskless lithography Henry I. SMITH
9:20 - 9:40	TEM study on the evolution of Ge nanocrystals in Si oxide matrix as a function of Ge concentration and the Si reduction process H.G. CHEW
9:40 - 10:00	Shape-controlled synthesis and chemically directed assembly of gold crystals Bruno X. LIU
10:00 - 10:20	Templated self-assembly of catalysts and scaffolds for nanotubes and nanowires Carl V. THOMPSON
10:20 - 10:40	Fabrication and I-V characterization of ZnO nanorod based metal-insulator- semiconductor junction Le Hong QUANG
10:40 - 11:00	Self-assembly for magnetic and electronic device fabrication Caroline A. ROSS
11:00 - 11:20	Tea Break
11:20 - 11:40	Nanomechanics experiments for engineered and biological materials C.T. LIM and S. SURESH
11:40 - 12:00	Engineering carbon nanotubes from first-principles N. MARZARI
12:00 - 12:20	Direct Control of the Conductance Channels in Carbon Nanotubes via Fluxional Handles Y.S. LEE
12:20 - 12:40	Native point defects in yttria as a high-dielectric-constant gate oxide material: a first-principles study J.X. ZHENG
12:40 - 13:00	Amorphous Al-transition metal alloys as anode material for lithium battery C.Y. WANG
13:00 - 13:20	Characterization of LiNi $_{0.5}$ Mn $_{1.5}$ O $_{4}$ thin film cathode prepared by pulsed laser deposition H. XIA
13:20 - 13:40	High temperature deformation behavior of in-situ bulk metallic glass matrix composites X.L. FU
13:40	End of Technical Parallel Session